

Supporting Information

Exploring Pristine and Transition Metal doped SiP₂ monolayer as a promising anode material for (Li, Na, Mg) Ion Batteries

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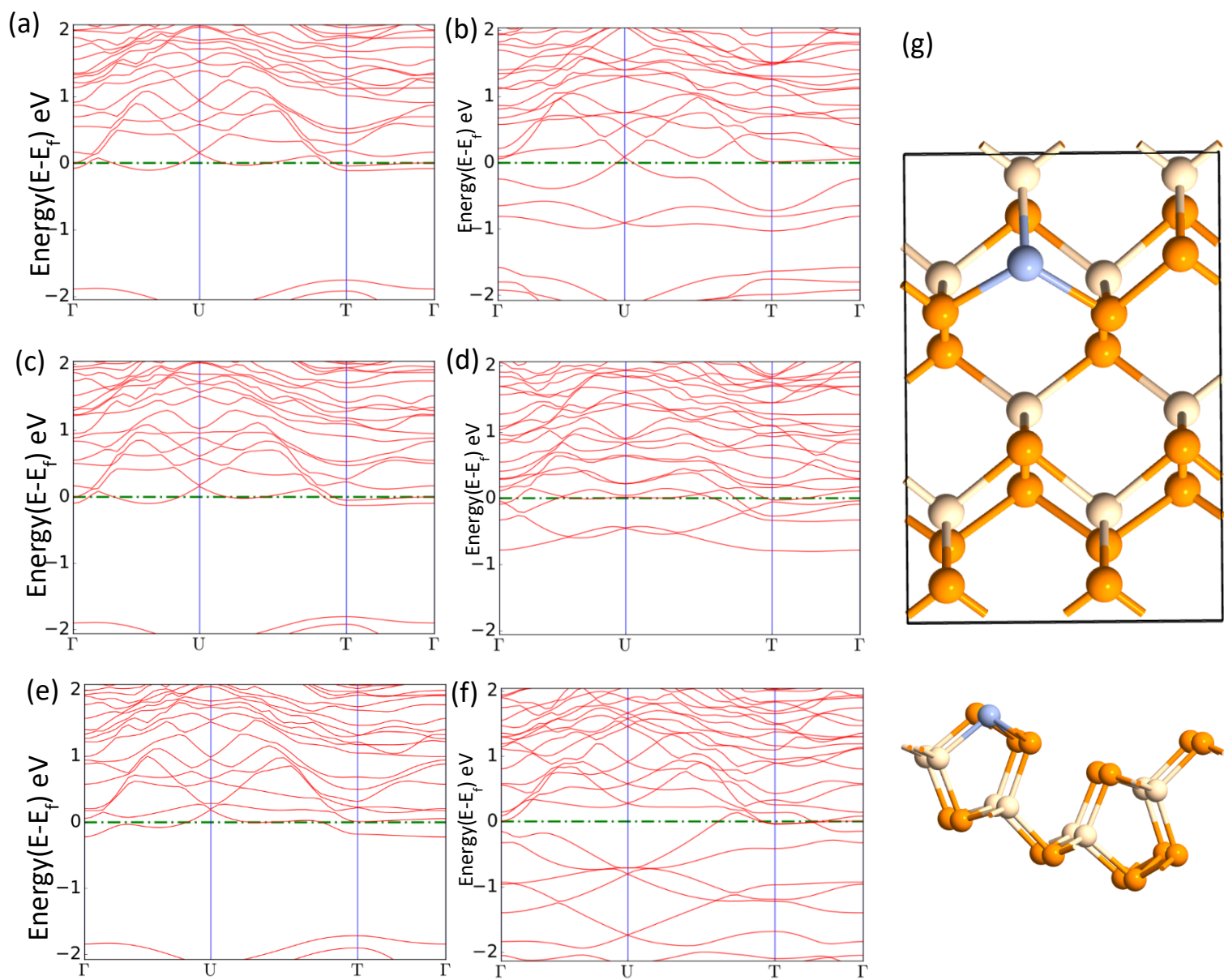


Fig S1: (a),(b) Band structure of single Li and Full Li adsorbed SiP₂ ; (c),(d) and (e),(f) band structure of Na and Mg atom with single and full adsorbed SiP₂ monolayers respectively,(g) doped SiP₂ monolayer

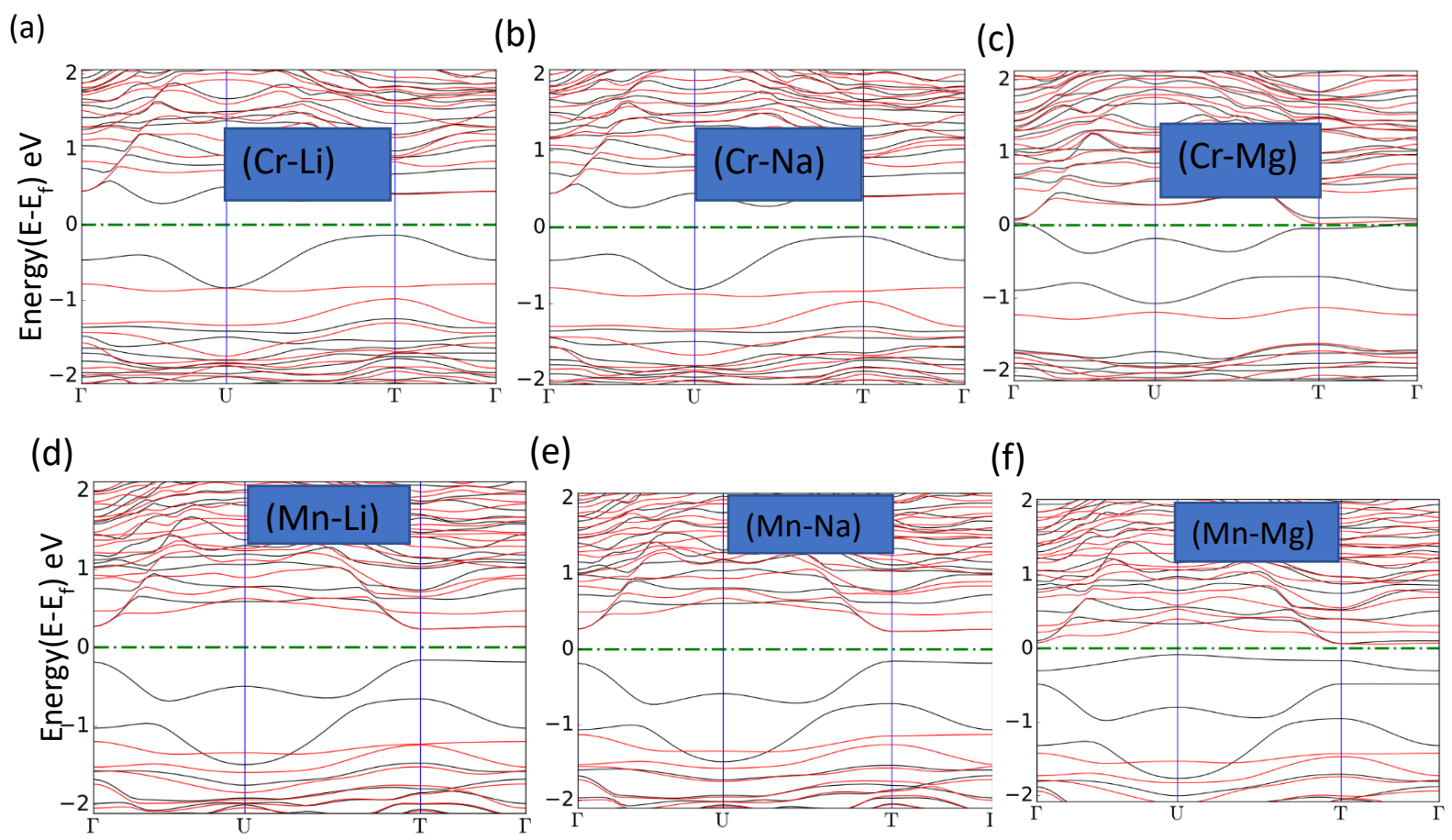


Fig S2: (a),(b),(c) and (d),(e),(f) are band structures of single Li, Na and Mg adsorbed on Cr and Mn-doped SiP₂ monolayers respectively

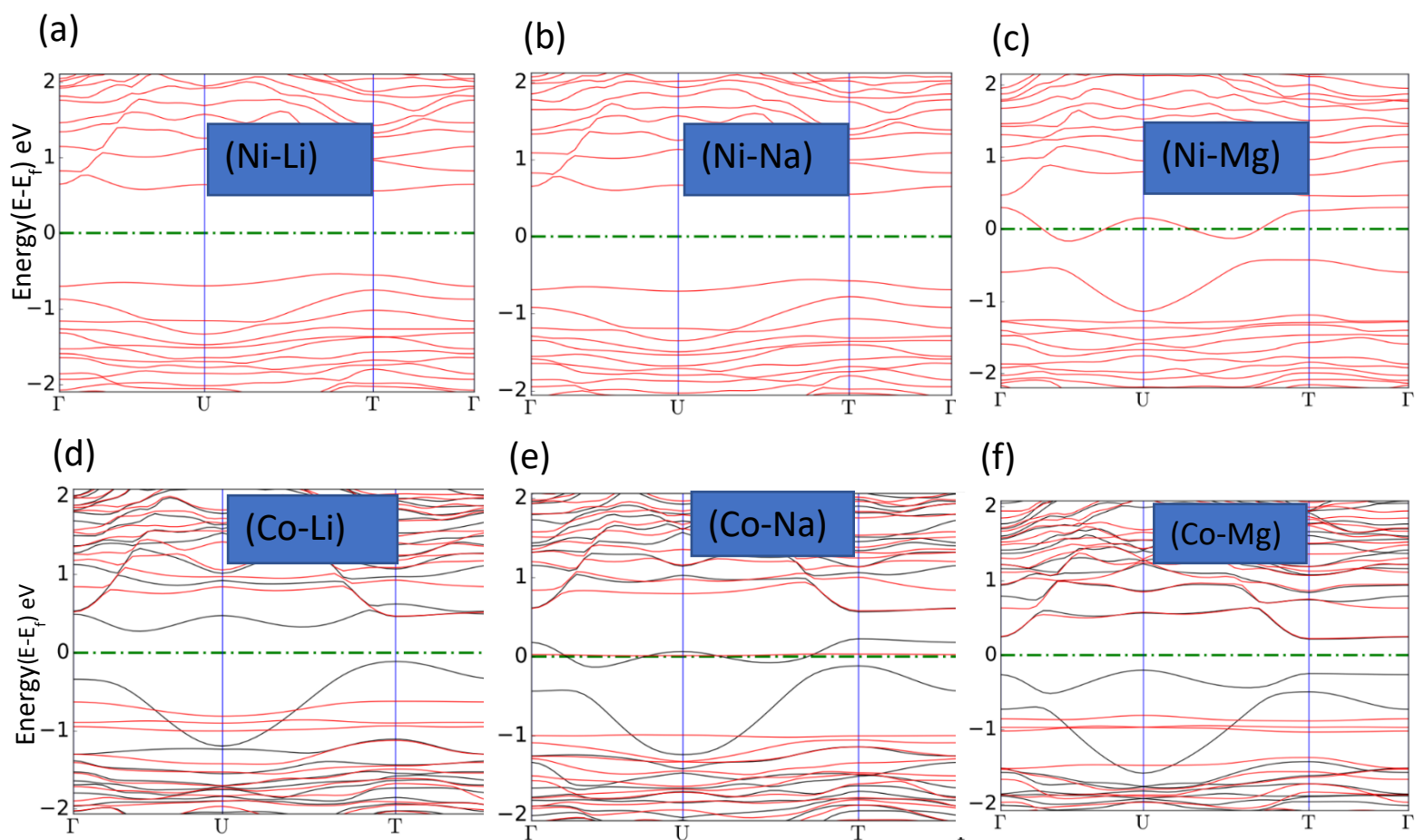


Fig S3: (a),(b),(c) and (d),(e),(f) are band structures of single Li, Na and Mg adsorbed on Ni and Co-doped SiP_2 monolayers respectively

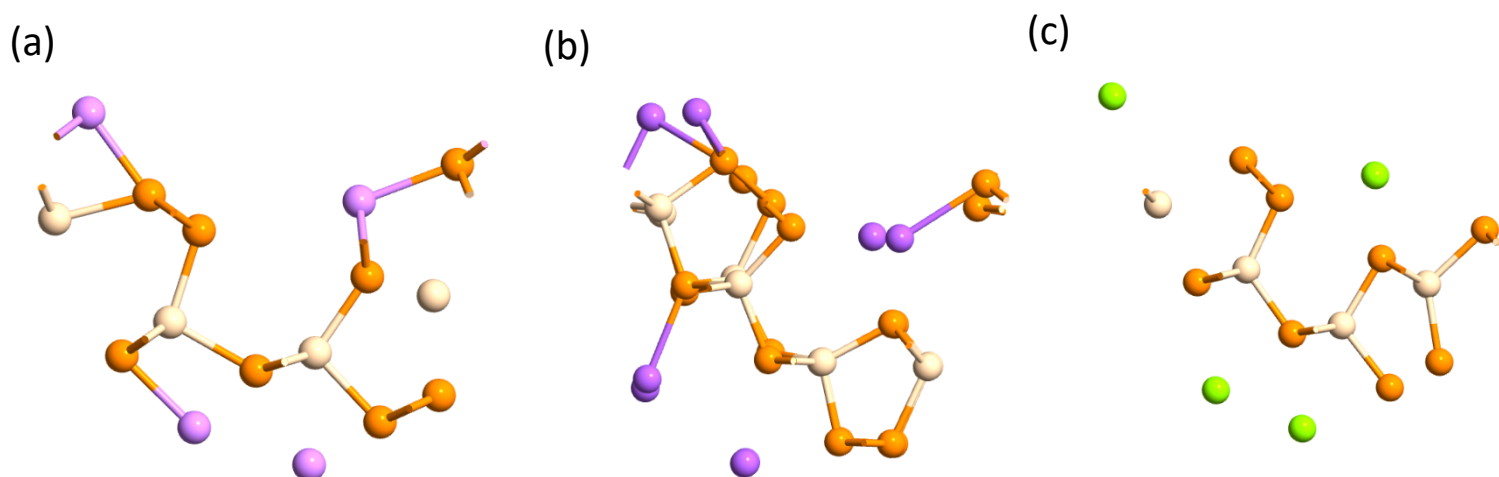


Fig S4: (a),(b),(c) represents 8 Li, Na and Mg atom adsorbed on SiP_2 monolayers respectively

Table S1: Formation energy for P and Si substituted by Transition metal on SiP₂ monolayer

Transition metal	E_{form} (eV) on P – substitution	E_{form} (eV) on Si – substitution
Cr	-2.59	-2.11
Mn	-2.21	-2.02
Ni	-1.91	-1.44
Co	-2.69	-2.09

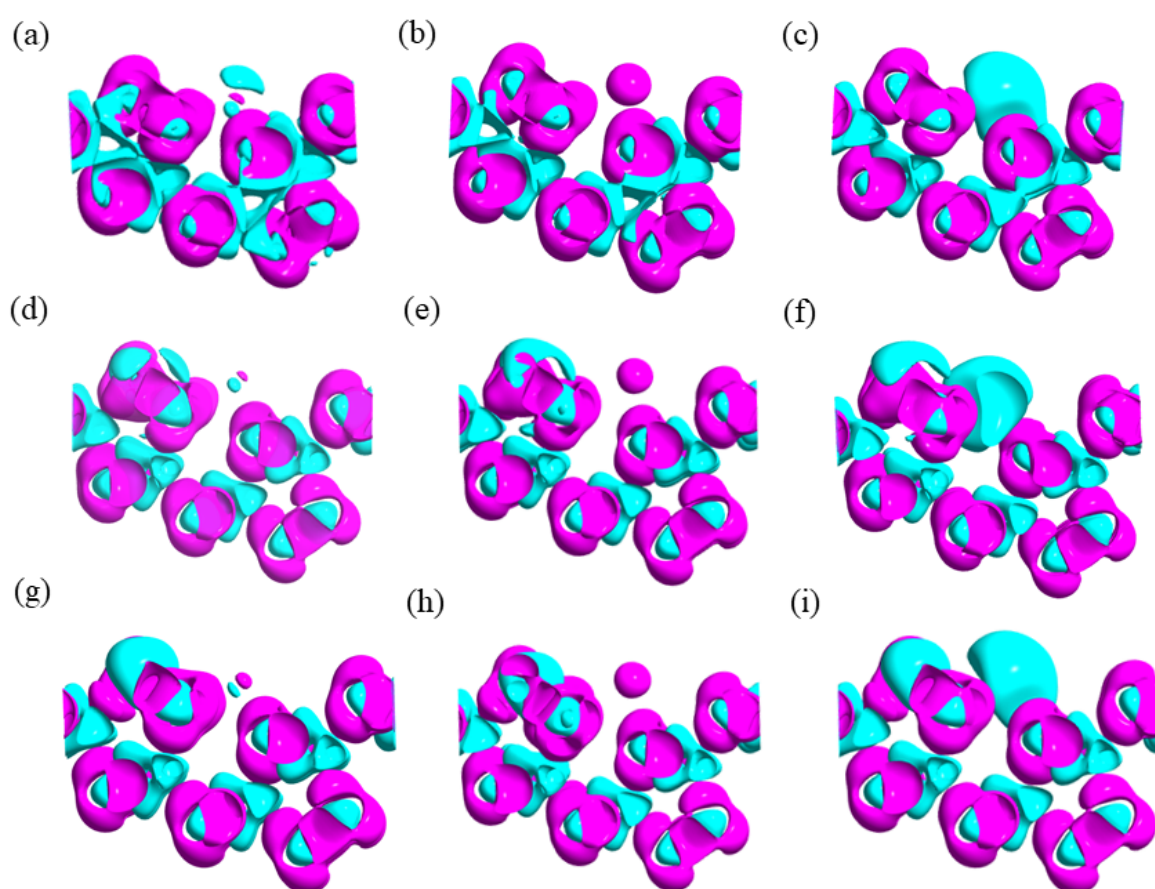


Fig S5: (a), (b) and (c) Isosurface plot for single Li, Na, and Mg adsorbed on pristine SiP₂ monolayer, (d),(e), (f) and(g), (h), (i) Isosurface plot for single Li, Na and Mg adsorbed on Co and Cr doped SiP₂ monolayer respectively.

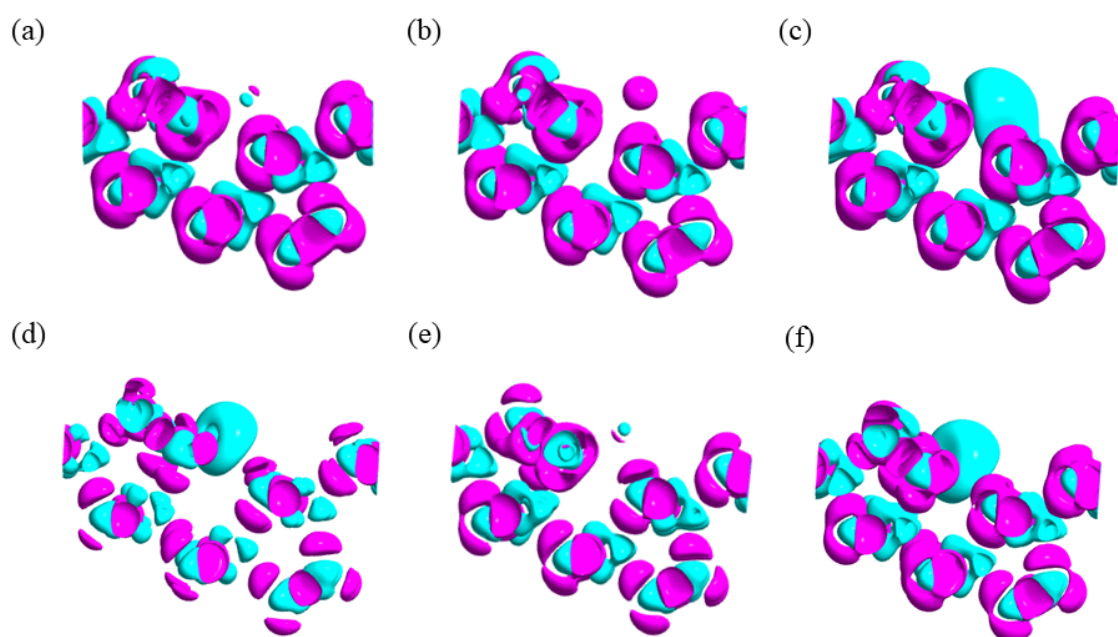


Fig S6: (a), (b),),(c) and (d),(e), (f) Isosurface plot for single Li, Na, and Mg adsorbed on Mn and Ni-doped SiP₂ monolayer respectively.

Brader Charge Analysis:

Table S2: Charge transfer ΔQ in the electronic unit (e) to the pristine and TM-doped SiP₂ monolayer

Metal atom	$\Delta Q(e)$ Pristine SiP ₂	$\Delta Q(e)$ Co-doped SiP ₂	$\Delta Q(e)$ Cr-doped SiP ₂	$\Delta Q(e)$ Mn-doped SiP ₂	$\Delta Q(e)$ Ni-doped SiP ₂
Li	0.68	0.39	0.31	0.36	0.31
Na	0.60	0.22	0.34	0.26	0.33
Mg	0.78	0.43	0.41	0.38	0.36

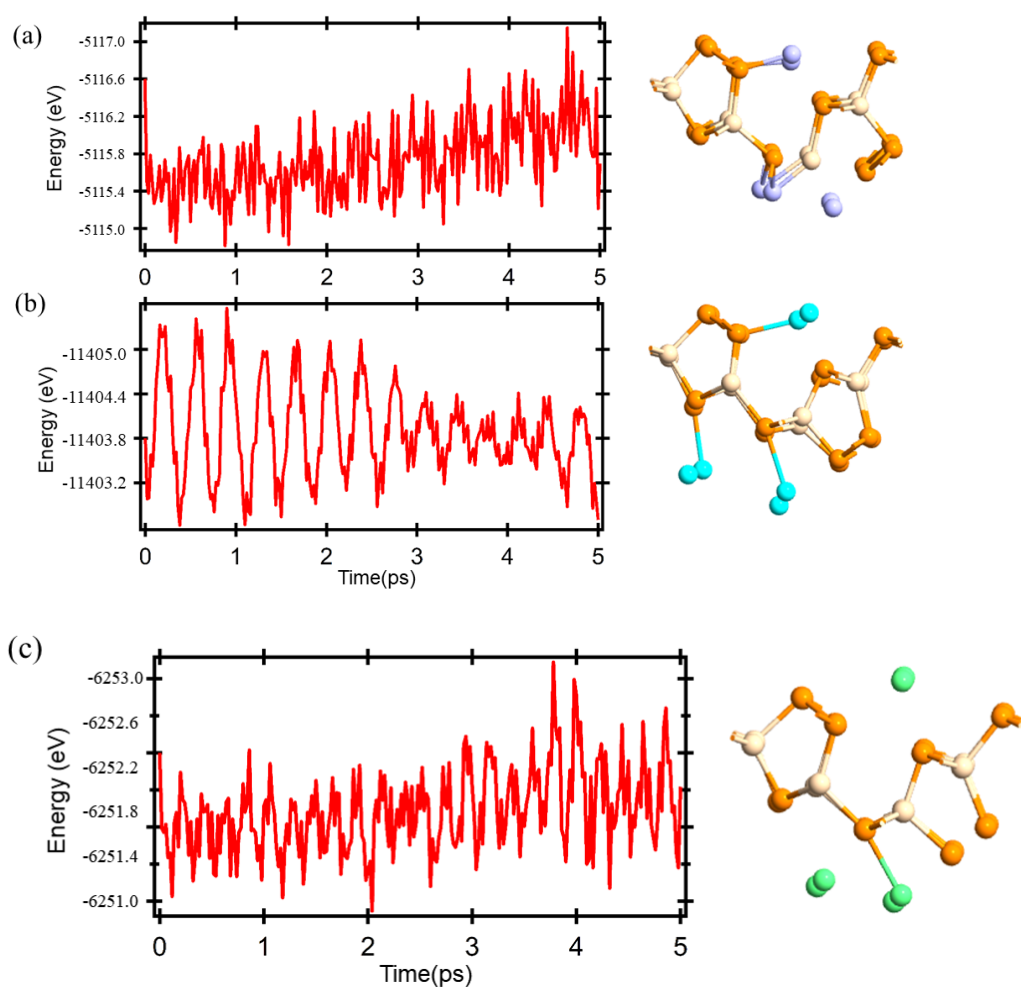


Fig S7: (a) Energy vs Time variation for of lithium adsorbed SiP₂ with the final structure at 300K, (b) and (c) Energy vs Time variation for full sodium and magnesium adsorbed SiP₂ with the final structure at 300K respectively.

Table S3: effective mass and carrier mobility

Carrier type	Effective mass (m^*)	Mobility(μ) $\text{cm}^2\text{V}^{-1}\text{s}^{-1}$
Electron (a)	1.56	9554.2
Hole(a)	1.99	257.5
Electron (b)	0.76	201.2
Hole(b)	1.13	2344.3